

(19) (KR)
(12) (A)

(51) 。 Int. Cl.⁷ (11) 10-2004-0027286
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(21) 10-2003-0034034
(22) 2003 05 28

(30) JP-P-2002-00284195 2002 09 27 (JP)

(71) 가 가 2 5 5

(72) 2-5-5 가 가
2-5-5 가 가
2-5-5 가 가
2-5-5 가 가

(74) :

(54)

R , G B 1 2 3 . R , G , B .

1 EL .
2 EL 1 R , G B EL
3 2 EL A-A .
4 EL EL EL

12:
51:
52:
70;
130: 1 TFT
140: 2 TFT

(Thin Film Transistor: TFT) (, EL) ,
가 가 , EL ,
EL 가 (, EL) , E
가 , 가 , 가 .
EL EL 가 (, R , B), EL EL
(, G) (, B) .
R , G B 가 R , G B 가 ,
R , G B 가

EL () , R , G B 가 , .
, EL (, 2001-93667).
EL
, R , G B

, 가 . , 가 .
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1
2
1 가 1 가
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1
가 , 2 가
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1
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2 , 2 ,
2
1
2 가

1
가

1
1

2

(, EL)

1 EL (, EL) EL

1 EL (, R) Rpix, (, B) Bpix가

R Rpix , B Bpix EL EL , G Gpix EL

pix , B Bpix가 , R Rpix, G Rpix, G B

PI , 가 G Gpix PI , B Bpix PI

R Rpix, G Gpix B Bpix

EL , R Rpix , G Gpix Rpix, G B Gpix B Bpix가

EL 가

PI

EL 가 , 가

G Gpix 가 Rpix , B Bpix 가

1 G Gpix 1 B Bpix . R Rpix 1 G Gpix 1 R Rpix B Bpix

$\times 2$ $\frac{2}{n} (n^2 \times n)$

$k \times k$

R Rpix , G Gpix B Bpix , $50\mu m$

, B Bpix, R Rpix, G Gpix

2 3 2 EL 1 R, G B EL

2, B Bpix가 R Rpix, G Gpix

2 (52) (51) (5)

1) EL (Indium Tin Oxide: ITO) 2 TFT(140)가 n 1 TFT(130)가 (70), EL

1 TFT(130) (13s) (55) (13d) 1 TFT(130) (11) 1 TFT(130) (51)

(70) Vsc SC (54) (11)(4) (55)

2 TFT(140) (43s) (43d) EL (12) 2 TFT(140)

40) (41) (55) (53)

R Rpix LR, G Gpix LG B Bpix LB, EL R Rpix LR

75.5 μ m, G Gpix B Bpix LG 56.5 μ m, B Bpix LB 66 μ m

3 (10) (11) (1)

1) 가 EL 2 TFT(140)가 (11) (11) () ()

13) 1 (15) 1 (15) (41) (11) (15) (15)

2 (18) (12) (12) 1 (15)

2 TFT(140) 2 (18) 2 (18) (12) (1)

2) (12) 2 (18) (16)

R Rpix, G (22), Gpix B (24) Bpix (16) (26)

(10) (22), (24) (26) 2 (18)

R Rpix, G Gpix B Bpix (22), (24) (26)

(28)

R Rpix, G EL (22, 24, 26) R Rpix (28) (22)

(28) 1 (28) 2 (28) 3 (24)

(26) B Bpix

(28) (22), (24) (26)

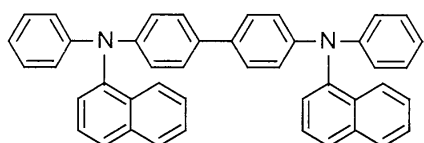
(22, 24, 26) (22, 24, 26) (28) , 3

(28) (30) (32) .
 EL (52) (51) 가 1 TFT(130)가 ,
 (41) (70) (70) (70) 2 TFT(140)
 가 , EL (53)

(12) , ITO, (SnO₂), (In₂O₃) .

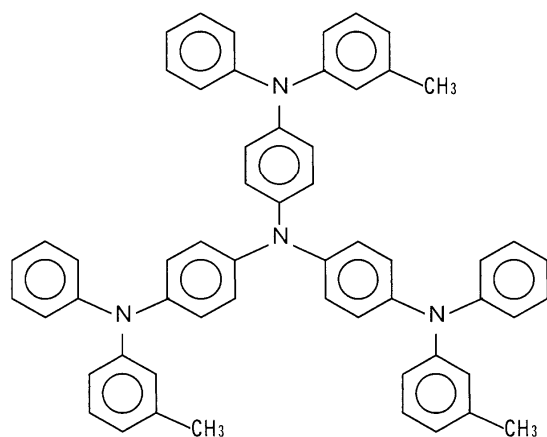
(16) , 1 N, N'- (-1-)-N, N'-
 - (N, N'-Di(naphthalen-1-yl)-N, N'-diphenyl-benzidine: , NPB) .

(1)



(16) , 2 4, 4', 4'- (3-
 (4, 4', 4'-tris(3-methylphenylphenylamino)triphenylamine: MTDATA) .

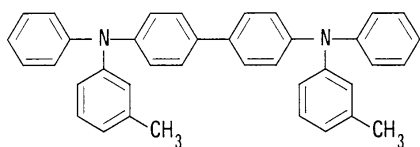
(2)



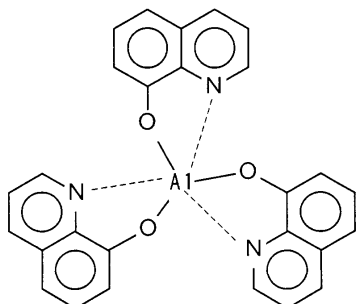
(16) , 3 N, N'- -N, N'- (3-)-1, 1'- -4, 4'-
 (N, N'-diphenyl-N, N'-di(3-methylphenyl)-1, 1'-biphenyl-4, 4'-diamine:TPD) .

(22) (24) , 4
 (Alq3), 5 가 (BeBq2) 1

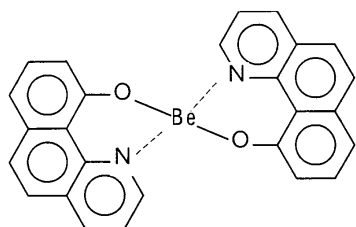
(3)



(4)

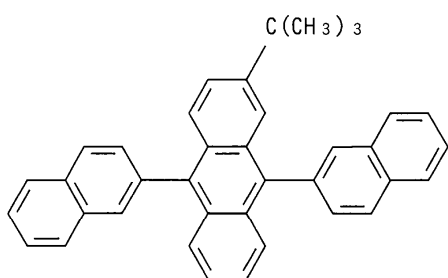


(5)



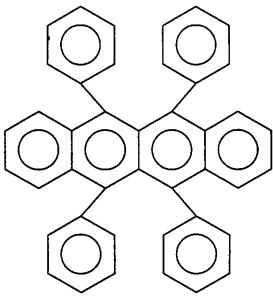
tert- , 가 . (, TBADN (26)) 6 EL ,

(6)

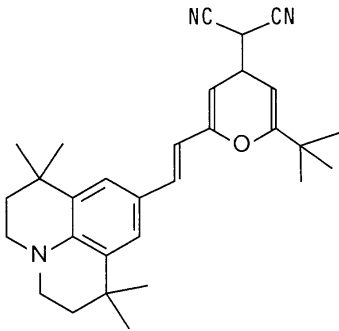


, (Rubrene), 8 2-(1, 1-)-6-(2-(2, 3, 6, 7- -1, 1, 7, 7- - , 5 - [ij] -9-))-4H- -4-) (2-(1, 1-Di methylethyl)-6-(2-(2, 3, 6, 7-tetrahydro-1, 1, 7, 7-tetramethyl- , 5 -benzoiqquinolizin-9-yl)ethenyl)-4H -pyran-4-ylidene)propanedinitrile: , DCJTB), 9 (Qui nacridone) , TBADN .

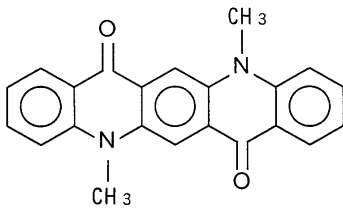
(7)



(8)



(9)



(28) , Alq3, BeBq2 가 .

(32) , (28) , (30) , (32) , 2 . ,

EL (22), (24) (26) (16) (22), (24)
 (26) (22, 24, 26) (28) 가 (28) . , ,
 (22, 24, 26) (28) (28)

가 , (22, 24, 26) (22, 24, 26) (28) 가
 , (22, 24, 26) (28) 가

4 EL . 4 EL EL 가
 , 3 (22) EL

4 (a) EL (22) 가 2 (18)
 . 4 (b) EL (22)
 . 4 (c) EL (22)

4 (a) (22) (2)
 8) , (12) 2 (18) EL
 , (22) (28) 가
 , (22, 24, 26) (28)
 가 .
 , 4 (b) (22) 가 (22)
 (28) , 4 (c) (22) 가 EL
 , 가 EL
 EL 가 , EL
 , R Rpix, G Gpix B Bpix (28)
 EL , (SiO₂ SiN) 가
 1 2 .

$$4\pi/\lambda (n_1d_1+n_2d_2+n_3d_3+\cdots+n_kd_k) = 2m\pi$$

$$4\pi/\lambda (n_1d_1+n_2d_2+n_3d_3+\cdots+n_kd_k) = (2m-1)\pi$$

m , n₁ n_k , d₁ d_k . ,

EL : =600 640[nm]

EL : =510 550[nm]

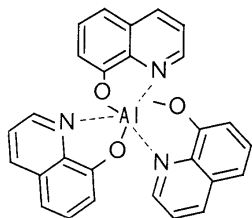
EL : =430 480[nm]

B , Bpix 1 2 EL R Rpix, G Gpix
 (28)

(12) ITO (16) 1900 NPB
 CVD () 100 CuPc()
 CF_x ()

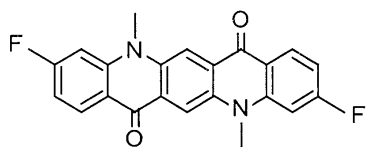
R Rpix , (22) 10 (8-)
 (Tris(8-hydroxyquinolino) aluminum: , Alq)
 20% (22) 350 , DCJTBB가 1.7%

(10)



G N'-N 20% Gpix (24) Alq (3, 4-Difluoro-N, N'-Dimethyl-quinacridone: (24) 350 11 , CFDMQA 3, 4-) 0.7% -N, TBAD

(11)



B) 1.5% (26) TBADN (26) 400 , tert- (, TBP

Al (28) Alq 4000 (30) 10 (32)

1 (28) 2 , R Rpix 350 , B Bpix (28) 250 , G Gpix 100 가

R Rpix, G Gpix B Bpix (28)

가 , R , 1 Rpix G 2 Gpix , (22, 24) (28) Alq

28) 1 (12) 1 (16) 2 (32) 2 , (

EL (28) (32) 가

(22, 24, 26) 가 (16)

(22), (24) (26) (22), 가 (24) (26)

(22), (24) (26)

(28) 가 2 (28) (28)

(16) (16) 가 2

(16)

가 , 가

(57)

1.

1 , 1 , 2 , 2

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가 , 가

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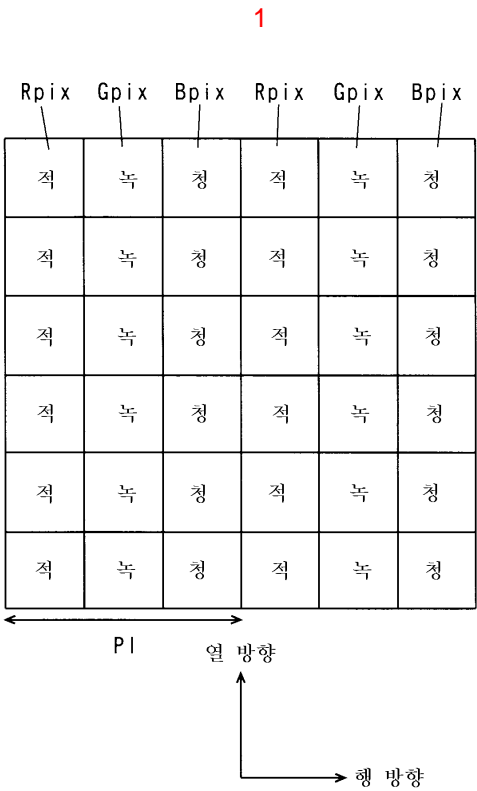
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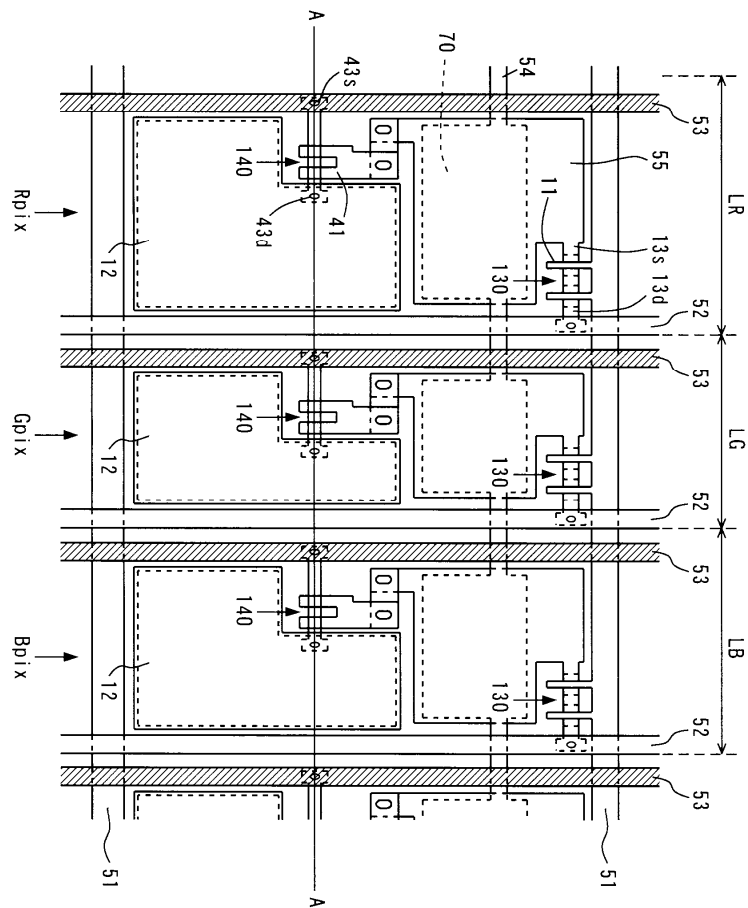
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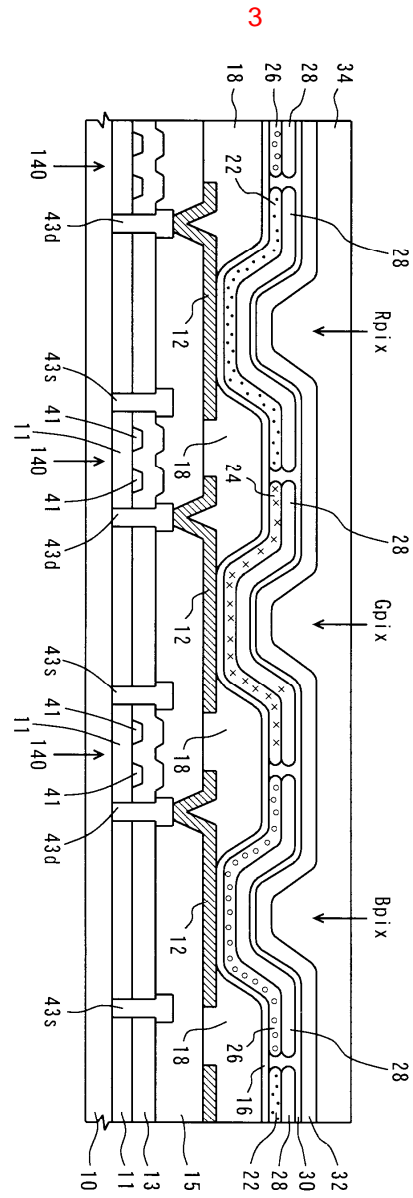
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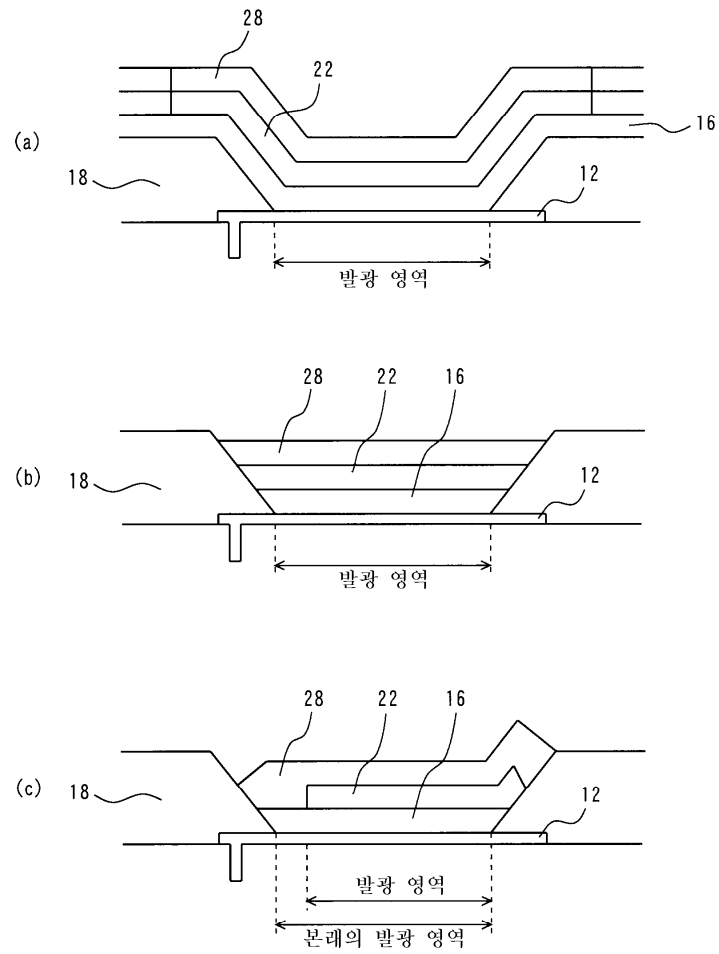


2





4



专利名称(译)	有机电致发光显示装置及其制造方法		
公开(公告)号	KR1020040027286A	公开(公告)日	2004-04-01
申请号	KR1020030034034	申请日	2003-05-28
[标]申请(专利权)人(译)	三洋电机株式会社 山洋电气株式会社		
申请(专利权)人(译)	三洋电机有限公司是分租		
当前申请(专利权)人(译)	三洋电机有限公司是分租		
[标]发明人	KANNO HIROSHI 간노히로시 HAMADA YUJI 하마다유지 MATSUKI HIROSHI 마쓰끼히로시 NISHIO YOSHITAKA 니시오요시따까		
发明人	간노히로시 하마다유지 마쓰끼히로시 니시오요시따까		
IPC分类号	H05B33/22 H01L51/50 H01L27/32 H05B33/12 H05B33/14 H01L51/56 H05B33/10 H01L51/00		
CPC分类号	H01L51/56 H01L27/3244 H01L51/0059 H01L51/006 H01L27/3211 H01L51/0071 Y10S428/917 H01L51/0054 H01L51/0072 H01L51/0058 H01L51/0081		
代理人(译)	CHU , 晟敏 LEE , JUNG HEE		
优先权	2002284195 2002-09-27 JP		
其他公开文献	KR100944861B1		
外部链接	Espacenet		

摘要(译)

发光层和R像素的电子传输层，形成在沿着列方向的条纹状的G像素和B像素。红色发光层和R像素的电子传输层被连续地通过使用在第一蒸发室中的共同掩模，绿色发射层，并在G像素的电子形成使用第二蒸发室中的公共掩模连续形成传输层，并且使用第三蒸发室中的公共掩模连续地形成B像素中的蓝色发光层和电子传输层。 1 指数方面 有机电致发光显示装置，掩模，沉积，载体传输层，

